



VN1160/ VN1160-1/ VN1160T

DIRECTION INDICATOR DRIVER FOR MOTORBIKE

TARGET SPECIFICATION

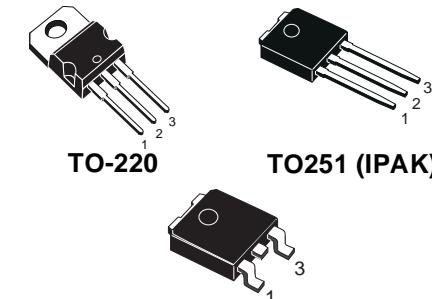
TYPE	R _{DS(on)}	I _{lim}	V _{CC}
VN1160			
VN1160-1	0.08 Ω	12 A	40 V
VN1160T			

- COMPLETE DIRECTION INDICATOR IN A 3 PIN PACKAGE
- REQUIRES ONLY ONE EXTERNAL CAPACITOR TO SET FLASHING FREQUENCY
- DOUBLE FREQUENCY FLASHING IN LOW LOAD CONDITIONS
- CYCLE BY CYCLE OVERTEMPERATURE SHUTDOWN
- REVERSE BATTERY PROTECTION

DESCRIPTION

The VN1160, VN1160-1, VN1160T are a monolithic device made by using STMicroelectronics VIPower technology, intended for building a complete flashing unit for two wheel vehicles. The device is connected between the battery positive terminal (V_{CC} pin) and a mechanical switch to the right and/or left bulbs. As soon as the series switch connects the OUT pin to the bulbs, the device begins to turn on/off with a 50% duty cycle.

An external low voltage capacitor (220μF, 10V)

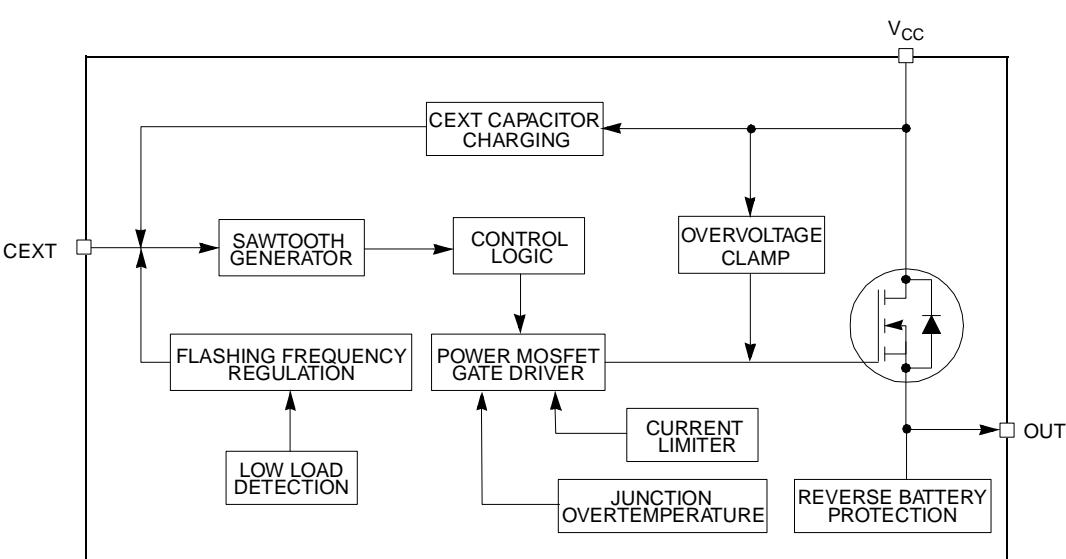


ORDER CODES

TO-252 (DPAK)	VN1160
TO-251 (IPAK)	VN1160-1
TO-220	VN1160T

connected between the CEXT pin and the OUT pin stores energy for powering the device during the ON phase and sets the flashing frequency. When a low load is detected (output current lower than I_{df}), flashing frequency is automatically doubled.

BLOCK DIAGRAM



VN1160/ VN1160-1/ VN1160T

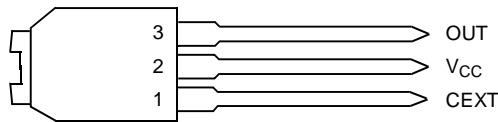
ABSOLUTE MAXIMUM RATING

Symbol	Parameter	Value			Unit
		TO-220	IPAK	DPAK	
V_{CC}	DC Supply Voltage		40		V
V_{dd}	CEXT Capacitor Voltage		6.5		V
I_D	Maximum DC drain Current		Internally Limited		A
- I_D	Reverse DC Output Current		- 5		A
V_{esd}	Electrostatic Discharge ($R=1.5\text{ k}\Omega$; $C=100\text{ pF}$)		2000		V
P_{tot}	Power Dissipation $T_C = 25^\circ\text{C}$	55	45	45	W
T_j	Junction Operating Temperature		Internally Limited		$^\circ\text{C}$
T_{stg}	Storage Temperature		- 55 to 150		$^\circ\text{C}$

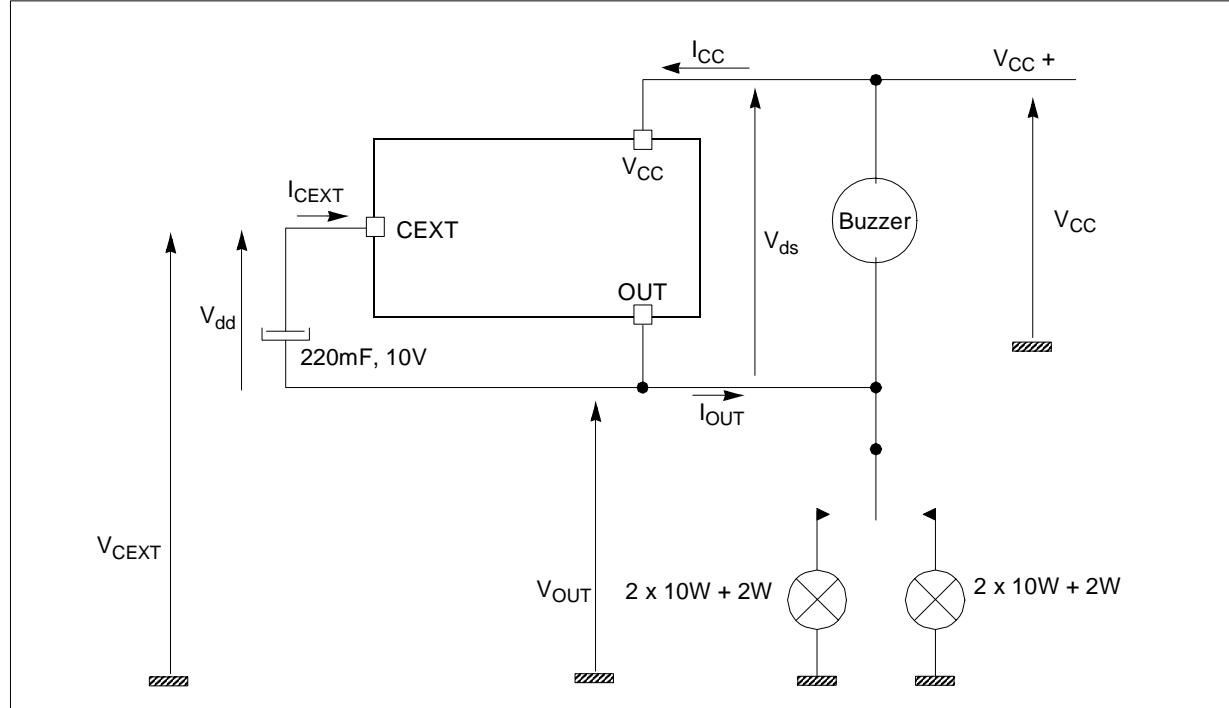
THERMAL DATA

Symbol	Parameter	Value			Unit
		TO-220	IPAK	DPAK	
$R_{thj-case}$	Thermal Resistance Junction-case	Max	2.2	3.33	$^\circ\text{C/W}$
$R_{thj-amb}$	Thermal Resistance Junction-ambient	Max	60	100	$^\circ\text{C/W}$

CONNECTION DIAGRAM (TOP VIEW)



CURRENT AND VOLTAGE CONVENTIONS



ELECTRICAL CHARACTERISTICS (9V<V_{CC}<16V; -20°C<T_j<85°C unless otherwise specified)
POWER

Symbol	Parameter	Test Conditions	Min	Typ	Max	Unit
V _{clamp}	V _{DS} Clamp Voltage	I _{OUT} =1.6A	40	45	50	V
I _{CEXT}	Supply Current from CEXT Pin	V _{DS} =0V; V _{dd} =5V; T _j =25 °C	810	880	950	μA
V _{ddcl}	CEXT Clamp Voltage	I _{CEXT} =2mA; V _{DS} =0V	TBD	7.2	TBD	V
V _{ddrcl}	CEXT Reverse Clamp Voltage	I _{CEXT} =-2mA; V _{DS} =0V	-1.0		-0.3	V
R _{ON}	On State Resistance	V _{dd} =5V; I _{OUT} =1.6A; T _j =25 °C			0.08	Ω

SWITCHING (V_{CC}=V_{en}=13.5V)

Symbol	Parameter	Test Conditions	Min	Typ	Max	Unit
dI/dt _(on)	Turn-on Current Slope	R _{LOAD} =8Ω		0.02		A/μs
dI/dt _(off)	Turn-off Current Slope	R _{LOAD} =8Ω		0.02		A/μs

DYNAMIC PARAMETERS

Symbol	Parameter	Test Conditions	Min	Typ	Max	Unit
f _{osc}	Self Oscillating Frequency	V _{CC} =13.5V; 220μF between CEXT and OUT; R _{LOAD} =8Ω	1.08	1.33	1.58	Hz
V _{ch}	Sawtooth High Level between CEXT and OUT	V _{CC} =13.5V		6		V
V _{cl}	Sawtooth Low Level between CEXT and OUT	V _{CC} =13.5V		4.5		V

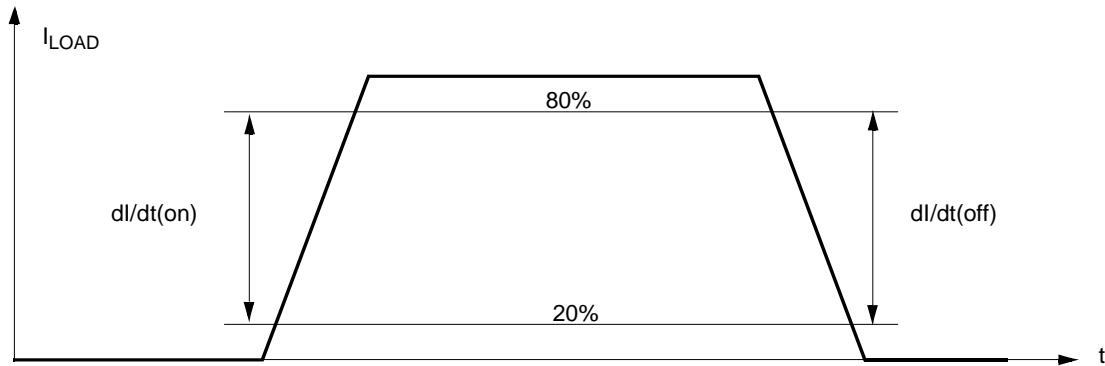
PROTECTIONS

Symbol	Parameter	Test Conditions	Min	Typ	Max	Unit
I _{lim}	Drain Current Limit	V _{dd} =5V; V _{DS} =13.5V		12		A
T _{jsh}	Overtemperature Shutdown		125			°C
T _{jrs}	Overtemperature Reset		100			°C
I _{df1}	Double Frequency Flashing Threshold	V _{CC} =9.5V (*)	816	940	1066	mA
I _{df2}	Double Frequency Flashing Threshold	V _{CC} =15.5V (*)	1062	1240	1417	mA

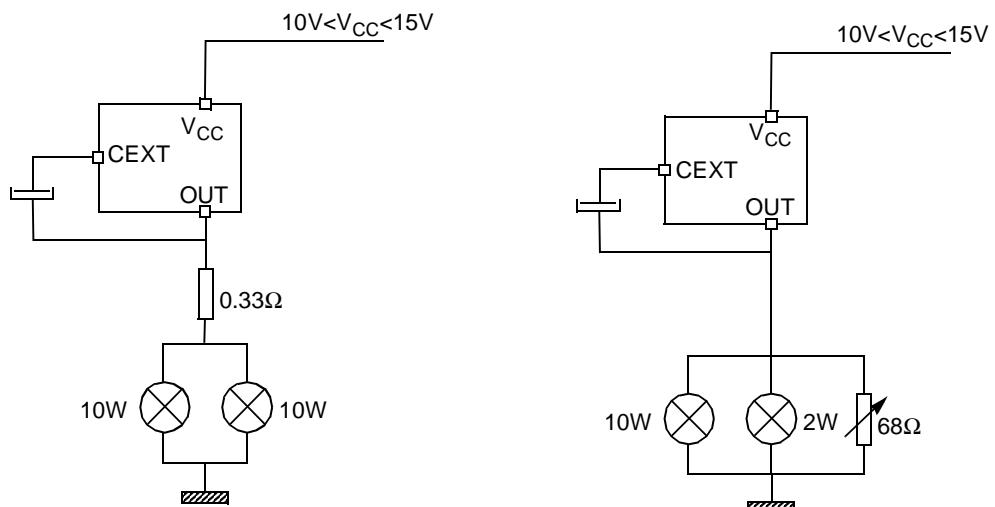
(*) See double frequency test configuration

VN1160/ VN1160-1/ VN1160T

SWITCHING CHARACTERISTICS



DOUBLE FREQUENCY TEST CONFIGURATION



FUNCTIONAL DESCRIPTION

1) Normal operation (see Fig.1)

When a nominal load (higher than a 20W bulb) is connected to the OUT pin, the device oscillates by charging the CEXT capacitor up to the threshold voltage V_{ch} quickly, and then slowly discharging CEXT to the threshold voltage V_{cl} by a constant current I_{CEXT} .
The self oscillating frequency of the device is determined by the relation :

$$f_{osc} = \frac{I_{CEXT}}{2 \times C_{EXT} \times (V_{ch} - V_{cl})}$$

The duty cycle is close to 50%.

2) Low load condition (see Fig.1)

If the load is lower than the load of a 14W bulb, the device will detect the low load at the end of the ON phase, and will double the oscillating frequency.

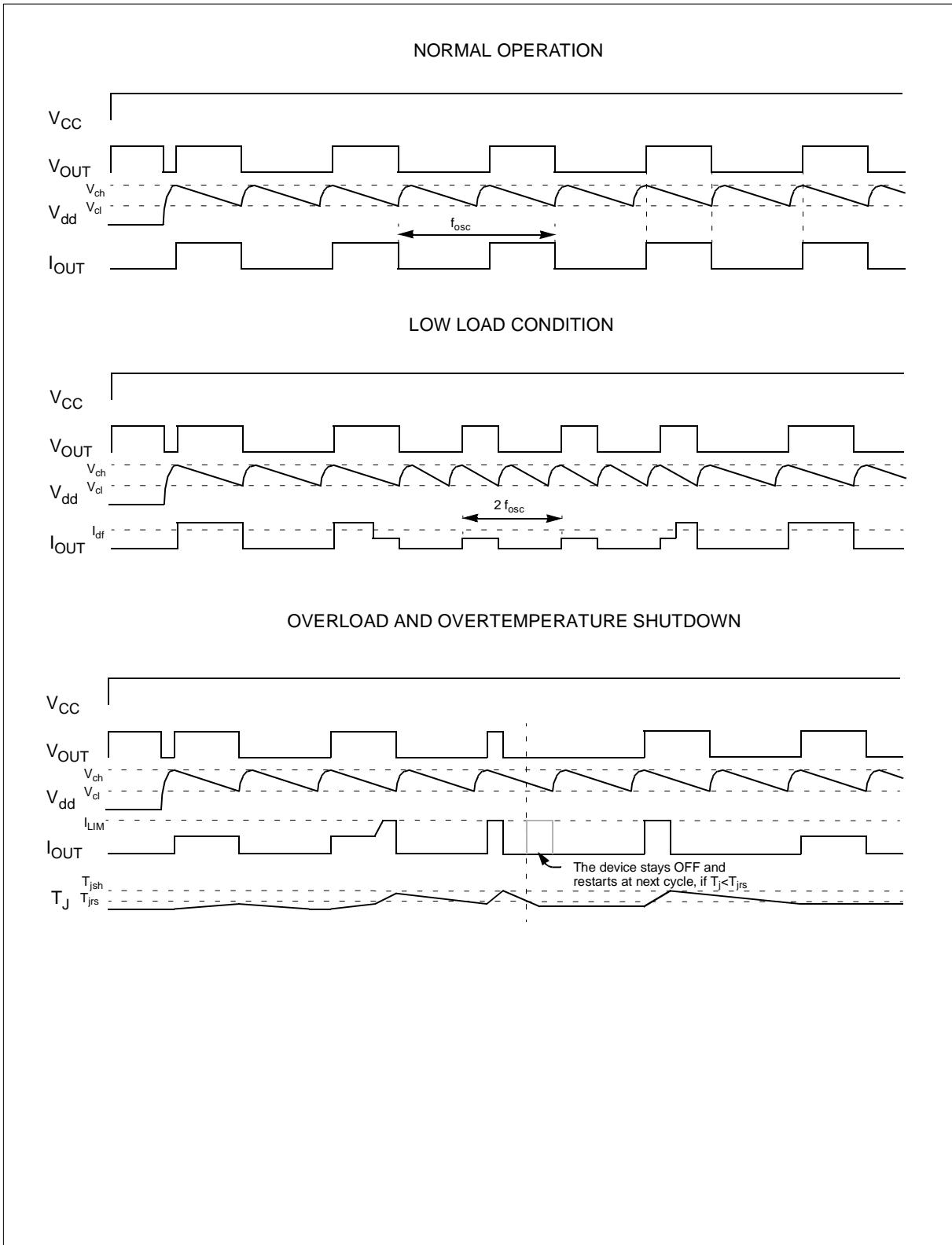
3) Overload and overtemperature shutdown (see Fig.1)

In the case of a short circuit of the load, the output current I_{OUT} is limited to the I_{LIM} value.

If the junction temperature becomes too hot ($T_j > T_{jsh}$), the device turns off, and waits for the next cycle to turn on providing that the junction temperature has cooled to below T_{jrs} .

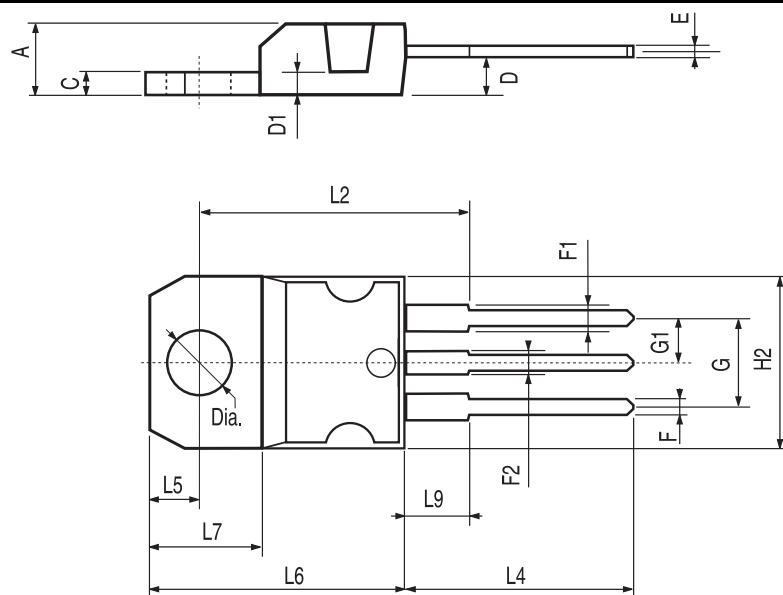
VN1160/ VN1160-1/ VN1160T

Figure1: Waveforms



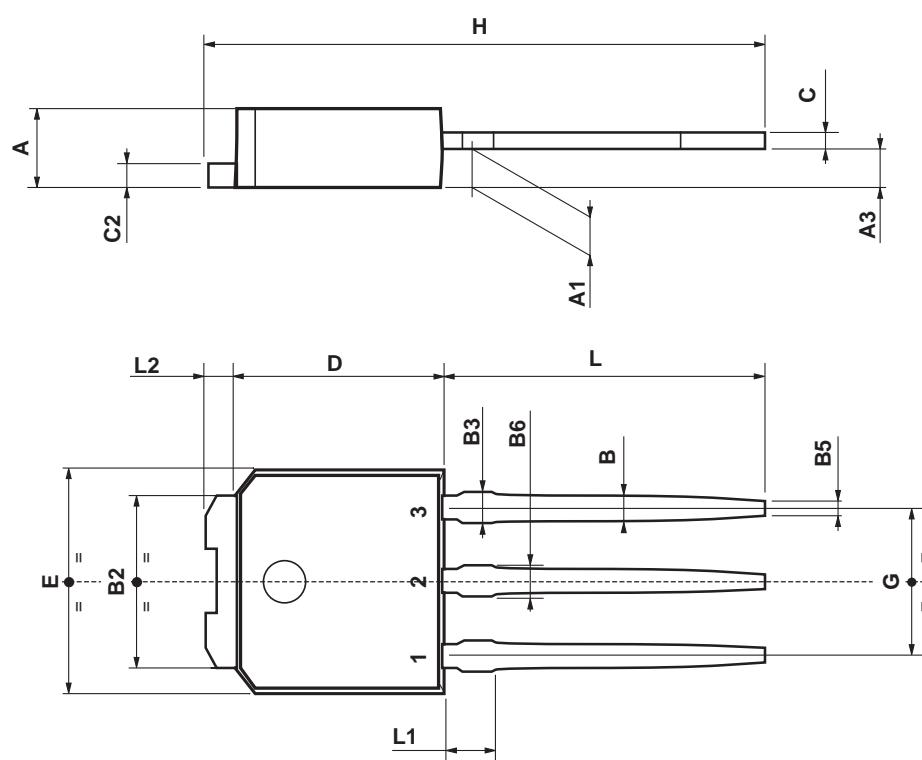
TO-220 MECHANICAL DATA

DIM.	mm.			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A	4.40		4.60	0.173		0.181
C	1.23		1.32	0.048		0.051
D	2.40		2.72	0.094		0.107
D1		1.27			0.050	
E	0.49		0.70	0.019		0.027
F	0.61		0.88	0.024		0.034
F1	1.14		1.70	0.044		0.067
F2	1.14		1.70	0.044		0.067
G	4.95		5.15	0.194		0.203
H2	10.0		10.40	0.393		0.409
L2		16.4			0.645	
L4	13.0		14.0	0.511		0.551
L5	2.65		2.95	0.104		0.116
L6	15.25		15.75	0.600		0.620
L7	6.2		6.6	0.244		0.260
L9	3.5		3.93	0.137	0.154	
DIA.	3.75		3.85	0.147		0.151



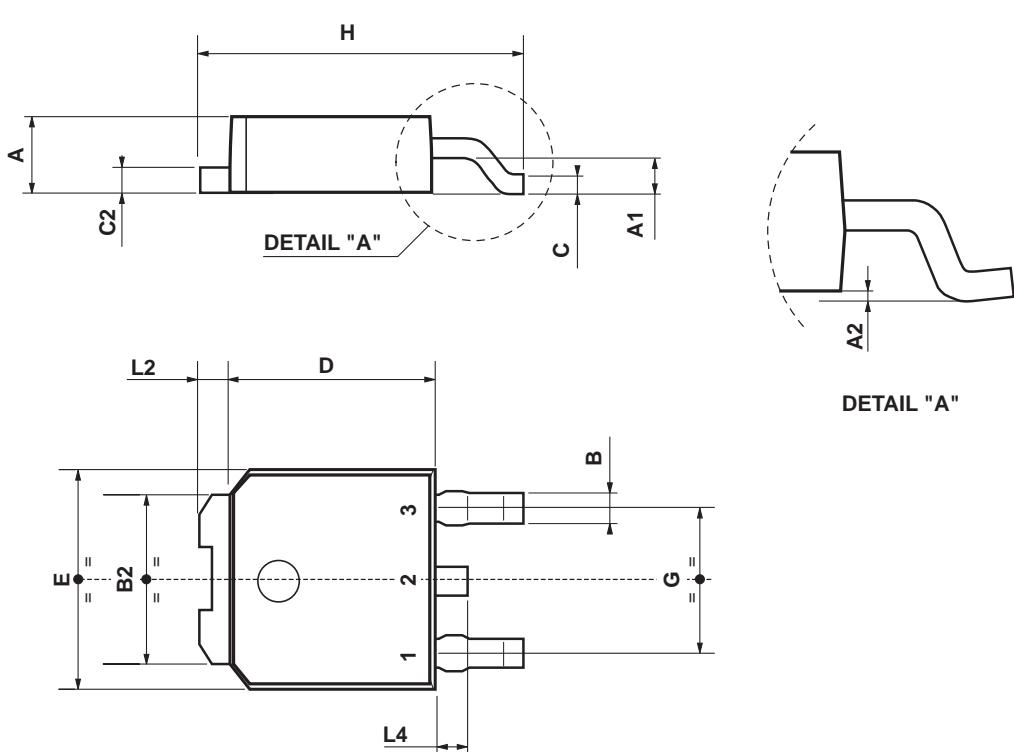
TO-251 (IPAK) MECHANICAL DATA

DIM.	mm.			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A	2.2		2.4	0.086		0.094
A1	0.9		1.1	0.035		0.043
A3	0.7		1.3	0.027		0.051
B	0.64		0.9	0.025		0.031
B2	5.2		5.4	0.204		0.212
B3			0.85			0.033
B5		0.3			0.012	
B6			0.95			0.037
C	0.45		0.6	0.017		0.023
C2	0.48		0.6	0.019		0.023
D	6		6.2	0.236		0.244
E	6.4		6.6	0.252		0.260
G	4.4		4.6	0.173		0.181
H	15.9		16.3	0.626		0.641
L	9		9.4	0.354		0.370
L1	0.8		1.2	0.031		0.047
L2		0.8	1		0.031	0.039



TO-252 (DPAK) MECHANICAL DATA

DIM.	mm.			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A	2.2		2.4	0.086		0.094
A1	0.9		1.1	0.035		0.043
A3	0.03		0.23	0.001		0.009
B	0.64		0.9	0.025		0.035
B2	5.2		5.4	0.204		0.212
C	0.45		0.6	0.017		0.023
C2	0.48		0.6	0.019		0.023
D	6		6.2	0.236		0.244
E	6.4		6.6	0.252		0.260
G	4.4		4.6	0.173		0.181
H	9.35		10.1	0.368		0.397
L2		0.8			0.031	
L4	0.6		1	0.023		0.039



VN1160/ VN1160-1/ VN1160T

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